

/ Descriptions

Silicon NPN transistor in a TO-251 Plastic Package.

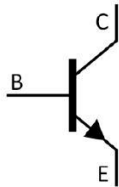
/ Features

Low $V_{CE(sat)}$, complementary to KTA1040I.

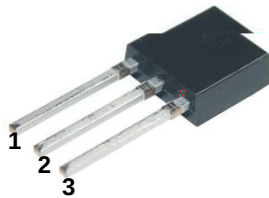
/ Applications

General purpose amplifier for surface mount applications.

/ Equivalent Circuit



/ Pinning



PIN1 Base PIN 2 Collector PIN 3 Emitter

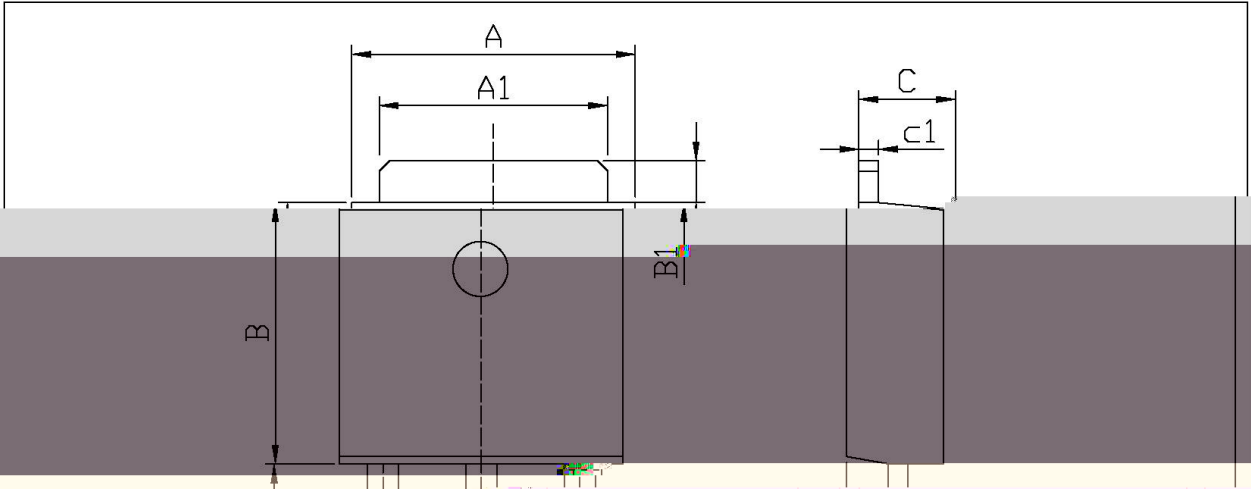
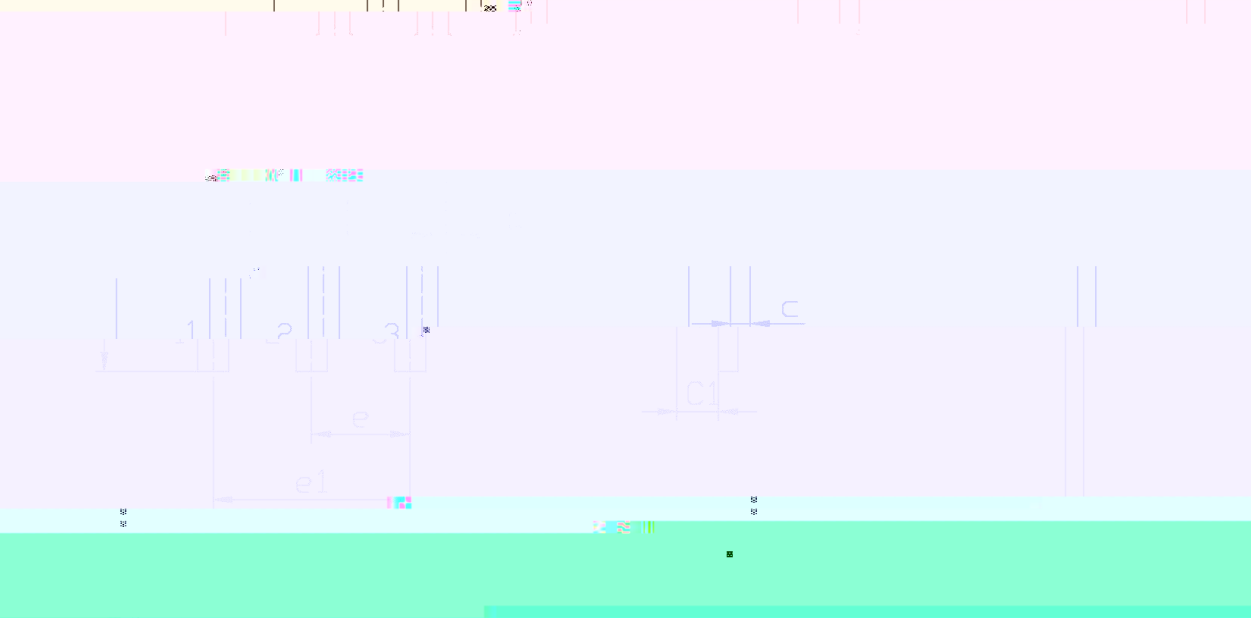
/ h_{FE} Classifications & Marking

h_{FE} Classifications Symbol	Y	GR
h_{FE} Range	100 200	150 300

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	60	V
Collector to Emitter Voltage	V_{CEO}	60	V
Emitter to Base Voltage	V_{EBO}	7.0	V
Collector Current - Continuous	I_C	3.0	A
Base Current - Continuous	I_B	0.5	A
Collector Power Dissipation	P_C	1.0	W
Collector Power Dissipation	$P_C(TC=25^\circ C)$	20	W
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55 ~ 150	

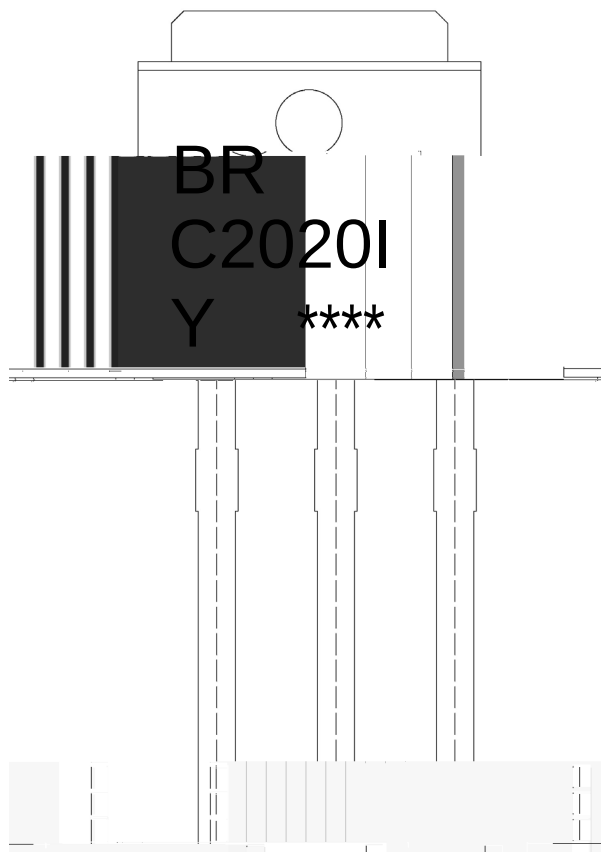
S10.5 0()TET55.6274 18refB10.5 0 0 10.5 702 0 0 702 340.14 611.00T0f55.62 51o0.00058 ref55.62

I Package Dimensions



Symbol	Max	Min	Max	Min	Symbol	Max	Min	Symbol	Max	Min
A	6.75	0.50	0.50	0.50	A1	5.50	0.50	B	6.75	0.50
B1	5.50	0.50	0.50	0.50	C	6.75	0.50	C1	5.50	0.50
e	2.50	2.00	2.00	2.00	e1	2.50	2.00			

/ Marking Instructions



Note:

BR: Company Code

C2020I: Product Type.

Y: h_{FE} Classifications Symbol

****: Lot No. Code, code change with Lot No.

(